

Fast CMOS 3.3V 16-Bit Bi-directional Transceiver

Features

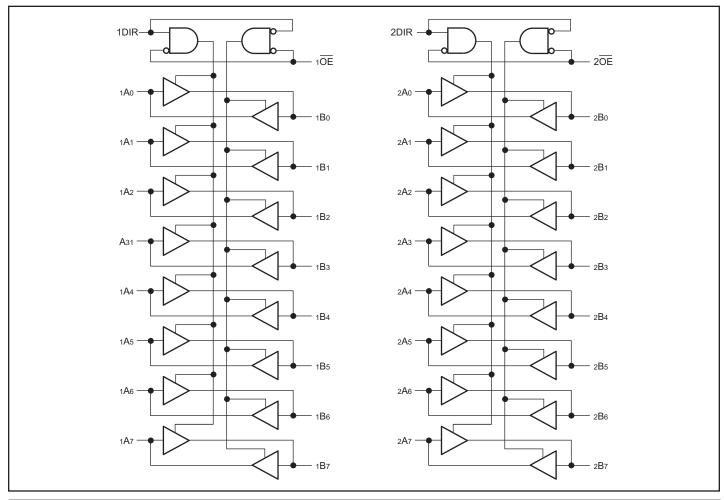
- Functionally compatible with FCT3, LVT, and 74 series 16245 families of products
- Tri-State outputs
- 5V Tolerant inputs and outputs
- 2.0V-3.6V V_{DD} supply operation
- Balanced sink and source output drives (24mA)
- Low ground bounce outputs
- · Power down High Impedance inputs and outputs
- Supports live insertion
- ESD Protection exceeds 2000V, Human Body Model 200V, Machine Model
- Packaging (Pb-free & Green available):
 - 48-pin 240-mil wide plastic TSSOP (A)
 - 48-pin 300-mil wide plastic SSOP (V)

Description

The PI74LCX16245 is a 16-bit bidirectional transceiver designed for asynchronous two-way communication between data buses. The direction control input pin (xDIR) determines the direction of data flow through the bidirectional transceiver. The Direction and Output Enable controls are designed to operate this device as either two independent 8-bit transceivers or one 16-bit transceiver. The output enable $(\overline{\rm OE})$ input, when HIGH, disables both A and B ports by placing them in HIGH Z condition.

The PI74LCX16245 can be driven from either 3.3V or 5.0V devices allowing this device to be used as a translator in a mixed 3.3/5.0V system.

Logic Block Diagram



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Product Pin Description

Pin Name	Description	
xOE	3-State Output Enable Inputs (Active LOW)	
xDIR	Direction Control Input	
xAx	Side A Inputs or 3-State Inputs	
xBx	Side B Outputs or 3-State Outputs	
GND	ND Ground	
$V_{_{ m DD}}$	Power	

Truth Table⁽¹⁾

Inputs		Outputs
xOE	xDIR	
L	L	Bus B Data to Bus A
L	Н	Bus A Data to Bus B
Н	X	Z

Notes:

- 1. H = High Voltage Level
 - X = Don't Care,
 - L = Low Voltage Level
 - Z = High Impedance

Product Pin Configuration

1 Todaet I in Comgatation				
1 ND 1	一、 戸	40 7 405		
1DIR [] 1		48 10E		
1B0 🛚 2		47 🛚 1 A 0		
1B1 ☐ 3		46 □ 1A1		
GND 4		45 🛛 GND		
1B2 ☐ 5		44 🗎 1 A 2		
1B3 ☐ 6		43 🛘 1A3		
V _{DD} ☐ 7		42 🗎 V _{DD}		
1B4 ☐ 8		41 🗎 1A4		
1B5 ☐ 9		40 🛘 1 A 5		
GND [10		39 🛘 GND		
1B6 ☐ 11		38 🛘 1A6		
1B7 ☐ 12	48-Pin	37 🛘 1A7		
2B0 ☐ 13	A, V	36 🛘 2A0		
2B1 ☐ 14		35 🛘 2A1		
GND ☐ 15		34 🗎 GND		
2B2 ☐ 16		33 🛘 2A2		
2B3 ☐ 17		32 🛘 2 A 3		
V _{DD} ☐ 18		31 🛘 V _{DD}		
2B4 ☐ 19		30 ☐ 2 A 4		
2B5 ☐ 20		29 🛘 2 A 5		
GND [21		28 🛘 GND		
2B6 ☐ 22		27 🛘 2A6		
2B7 ☐ 23		26 🛘 2A7		
2DIR ☐ 24		25 🛘 2 OE		



Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature65°C to +1:	50°C
Ambient Temperature with Power Applied40°C to +8	35°C
Supply Voltage to Ground Potential (Inputs & $V_{\rm DD}$ Only)–0.5V to +	7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only)0.5V to +	7.0V
DC Input Voltage0.5V to +	7.0V
DC Output Current	0mA
Power Dissipation	.0W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions

Symbol	Parameter		Min.	Max.	Units
W	Cumply Voltage	Operating	2.0	3.6	
$V_{_{ m DD}}$	V _{DD} Supply Voltage	Data Retention	1.5	3.6	
V _I	Input Voltage		0	5.5	V
V O don't Wilder	Output Voltage	High or Low State	0	$V_{_{ m DD}}$	
V _o	Output voltage	3-State	0	5.5	
I /I		$V_{DD} = 3.0V - 3.6V$	-	±24	
I _{OH} /I _{OL} Output Current	$V_{DD} = 2.7V$	-	±12	mA	
T _A	Free-Air Operating Temperature		-40	85	°C
$\Delta t/\Delta V$	Input Edge Rate	$V = 0.8V - 2.0V, V_{DD} = 3.0V$	0	10	ns/V



DC Electrical Characteristics (Over the Operating Range, $T_A = -40$ °C to +85°C, $V_{DD} = 2.7$ V to 3.6V)

Parameters	Description	Test Co	onditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
$V_{_{ m IH}}$	Input HIGH Voltage	Guaranteed Logic 1	HIGH Level	2.0			
V _{IL}	Input LOW Voltage	Guaranteed Logic 1	LOWLevel			0.8	
		$V_{DD} = 2.7 - 3.6$	$I_{OH} = -0.1 \text{mA}$	V _{DD} -0.2			
N/	Output IIICII Valtaga	$V_{DD} = 2.7$	$I_{OH} = -12mA$	2.2			
V_{OH}	Output HIGH Voltage	V - 2.0	$I_{OH} = -18 \text{mA}$	2.4			
		$V_{DD} = 3.0$	$I_{OH} = -24 \text{mA}$	2.2			V
		$V_{DD} = 2.7 - 3.6$	$I_{OL} = 0.1 \text{mA}$			0.2	
17	Output LOW Voltage	$V_{\rm DD} = 2.7$	$I_{OL} = 12mA$			0.4	
V _{OL}		$V_{DD} = 3.0$	$I_{OL} = 16 \text{mA}$			0.4	
			$I_{OL} = 24mA$			0.55	
V _{IK}	Clamp Dioide Voltage	$V_{DD} = Min., I_{IN} = -1$	18mA		-0.7	-1.2	
I	Input Leakage Current	$0 \le V_I \le 5.5V$	$V_{DD} = 2.7 - 3.6$			±5	
I_{OZ}	Tri-State Output Leakage	$0 \le V_{O} \le 5.5V$ $V_{I} = V_{IH} \text{ or } V_{IL}$	$V_{DD} = 2.7 - 3.6$			±5	
I _{OFF}	Power Down Disable	$V_{DD} = 0V$, V_{IN} or V	$_{\rm OUT} \le 5.5 \rm V$			10	μΑ
I_{DD}	Quiescent Power supply current	$V_{DD} = Max.$	$V_{IN} = GND \text{ or } V_{DD}$		0.1	10	
$\Delta I_{ m DD}$	Quiescent Power supply current TTL Inputs High	$V_{DD} = Max.$	$V_{IN} = V_{DD} = 0.6V^{(3)}$			500	

Notes:

- For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type. Typical values are at $V_{DD} = 3.3 V$, $+25^{\circ}C$ ambient. Per TTL driven input; all other inputs at V_{DD} or GND.

Capacitance

Parameters	Description	Test Conditions	Тур.	Units
C_{IN}	Input Capacitance	$V_{DD} = Open, V_{I} = 0V \text{ or } V_{DD}$	7	
C_{OUT}	Output Capacitance	$V_{DD} = 3.3 \text{V}, V_{I} = 0 \text{V or } V_{DD}$	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{DD} = 3.3 \text{V}, V_{I} = 0 \text{V or } V_{DD}, F = 10 \text{ MHz}$	20	

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Switching Characteristics over Operating Range

Parameters Description		Description Test Conditions		$V_{DD} = 3.3V \pm 0.3$		$V_{DD} = 2.7V$	
rarameters	Description	Test Conditions	Min.	Max.	Min.	Max.	Units
$t_{_{\mathrm{PHL}}}$	Propagation Delay, D _{XX} to O _{XX}		1.5	4.5	1.5	5.2	
t _{PZH}	Output Enable time	$C_r = 50pF$	1.5	6.5	1.5	7.2	
$t_{_{\mathrm{PHZ}}}$	Output Disable time	$C_{L} = 50 \text{pF}$ $R_{L} = 500 \Omega$	1.5	6.4	1.5	3.9	ns
t _{sk(0)}	Output Skew ⁽¹⁾			1.0			

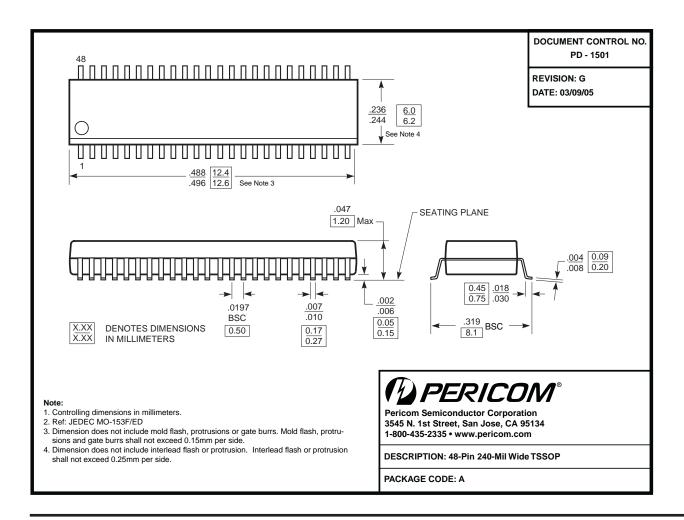
Note:

Dynamic Switching Characteristics $(T_A = +25^{\circ}C)$

Parameters	Description	Test Conditions ⁽¹⁾	Тур.	Units
V_{OLP}	Dynamic LOW peak voltage	$V_{DD} = 3.3 \text{V}, C_{L} = 50 \text{pF},$	0.8	V
V _{OLV}	Dynamic LOW valley voltage	$V_{IH}^{BB} = 3.3 \text{ V}, V_{IL}^{B} = 0 \text{ V}$	0.8	·

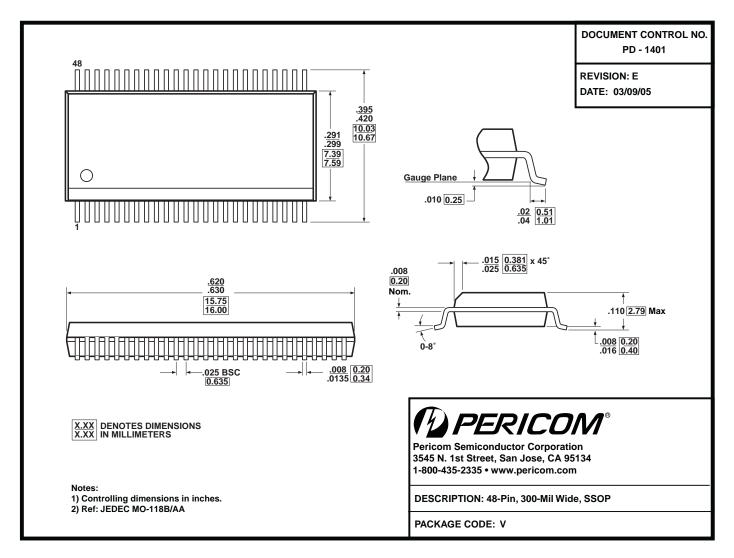
Note:

Measured with 15 outputs switching from High-to-Low or Low-to-High. The remaining output is measured in the LOW state.



^{1.} Skew between any two outputs, of the same package, switching in the same direction.





Note:

• For latest package info, please check: http://www.pericom.com/products/packaging/mechanicals.php

Ordering Information

Ordering Code	Package Type	Package Description
PI74LCX16245AEX	A	Pb-free & Green, 48-Pin 240-mil wide Plastic TSSOP (A)
PI74LCX16245VEX	V	Pb-free & Green, 48-Pin 300-mil wide Plastic TVSOP (A)

Notes:

- · Thermal characteristics can be found on the company web site at www.pericom.com/packaging/
- E = Pb-free & Green
- Adding an X suffix = Tape/Reel

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